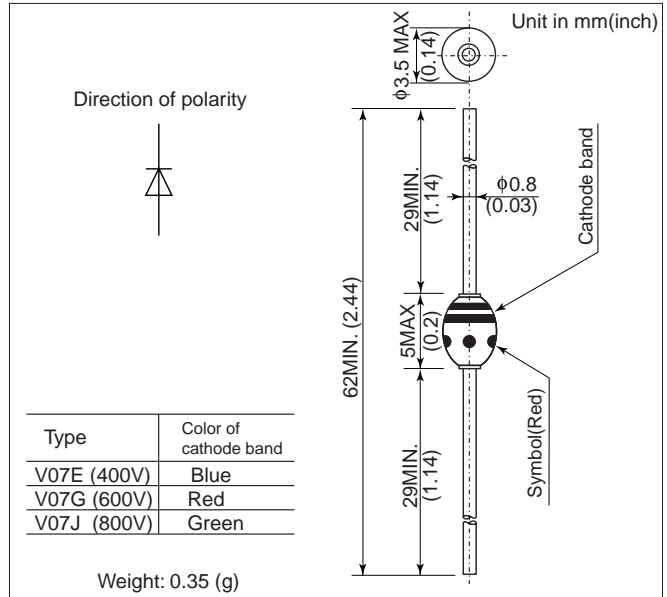


# V07

## FEATURES

- Transient surge voltage protection.
- Diffused-junction. Glass passivated and encapsulated.

## OUTLINE DRAWING



## ABSOLUTE MAXIMUM RATINGS

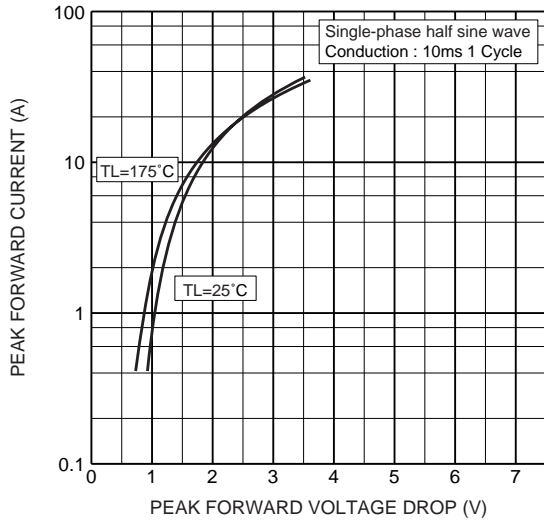
Items	Type	V07E	V07G	V07J	
Repetitive Peak Reverse Voltage	$V_{RRM}$	V	400	600	800
Peak Reverse Power	$P_{RM}$	W	40( $T_j = 165^\circ\text{C}$ , Pulse duration 1ms Non-repetitive )		
Average Forward Current	$I_{F(AV)}$	A	1.3 ( Single-phase half sine wave $180^\circ$ conduction $T_L=90^\circ\text{C}$ , Lead length = 10mm )		
Surge(Non-Repetitive) Forward Current	$I_{FSM}$	A	40( Without PIV, 10ms conduction, $T_j = 175^\circ\text{C}$ start )		
$I^2t$ Limit Value	$I^2t$	$\text{A}^2\text{s}$	6.4( Time = 2 ~ 10ms, I = RMS value )		
Operating Junction Temperature	$T_j$	$^\circ\text{C}$	-65 ~ +175		
Storage Temperature	$T_{stg}$	$^\circ\text{C}$	-65 ~ +200		

- Notes (1) Lead mounting : Lead temperature  $300^\circ\text{C}$  max. to 3.2mm from body for 5sec. max..  
 (2) Mechanical strength : Bending  $90^\circ \times 2$  cycles or  $180^\circ \times 1$  cycle, Tensile 2kg, Twist  $90^\circ \times 1$  cycle.

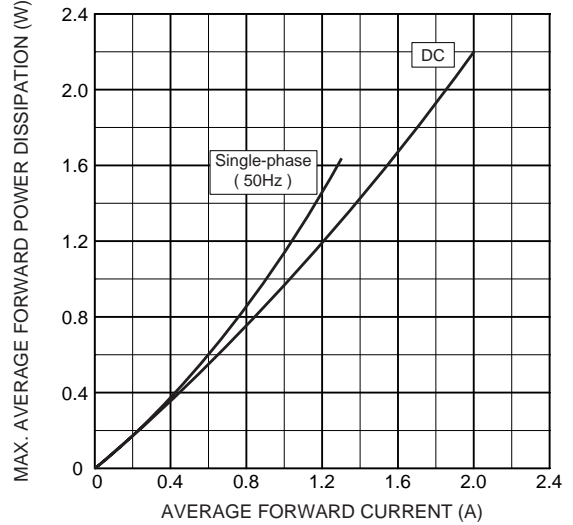
## CHARACTERISTICS( $T_L=25^\circ\text{C}$ )

Items	Symbols	Units	Min.	Typ.	Max.	Test Conditions
Peak Reverse Current	$I_{RRM}$	$\mu\text{A}$	—	0.6	10	All class, Rated $V_{RRM}$
Peak Forward Voltage	$V_{FM}$	V	—	—	1.1	$I_{FM}=1.3A_p$ , Single-phase half sine wave 1 cycle
Reverse Recovery Time	$t_{rr}$	$\mu\text{s}$	—	3.0	—	$I_F=2\text{mA}$ , $V_R=-15\text{V}$
Avalanche Voltage	$V_{AVL}$	V	$V_{RRM}$	—	1600	$I_{RM}=1.0\text{mA}$ , Single-phase half sine wave 1 pps, Time $\leq 5\text{s}$
Steady State Thermal Impedance	$R_{th(j-a)}$	$^\circ\text{C}/\text{W}$	—	—	80	Lead length = 10 mm
	$R_{th(j-l)}$				50	

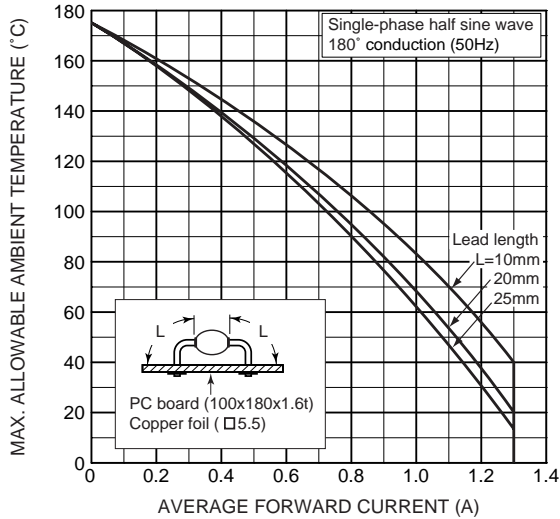
Forward characteristics



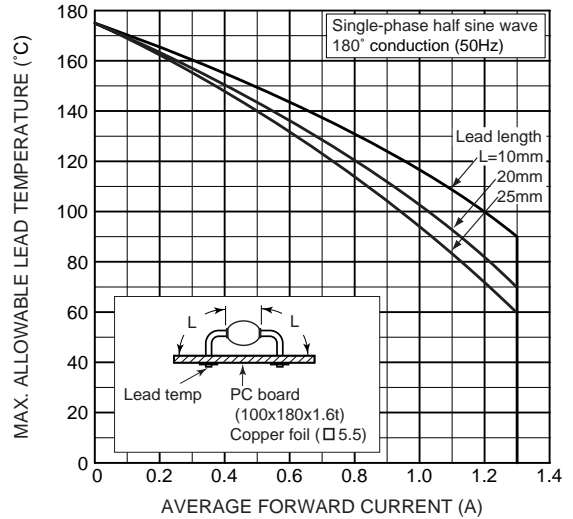
Max. average forward power dissipation (Resistive or inductive load)



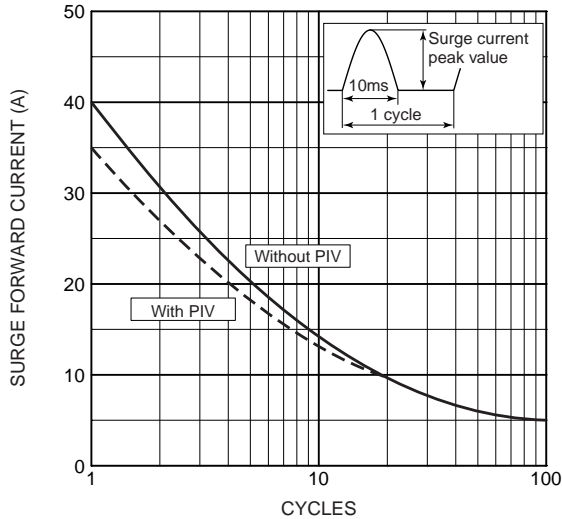
Max. allowable ambient temperature (Resistive or inductive load)



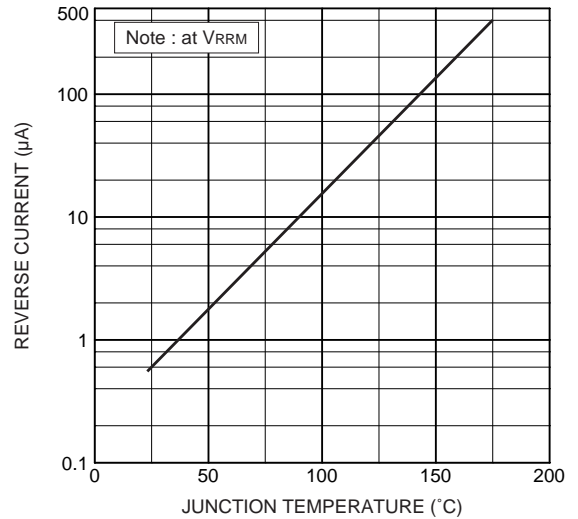
Max. allowable lead temperature (Resistive or inductive load)



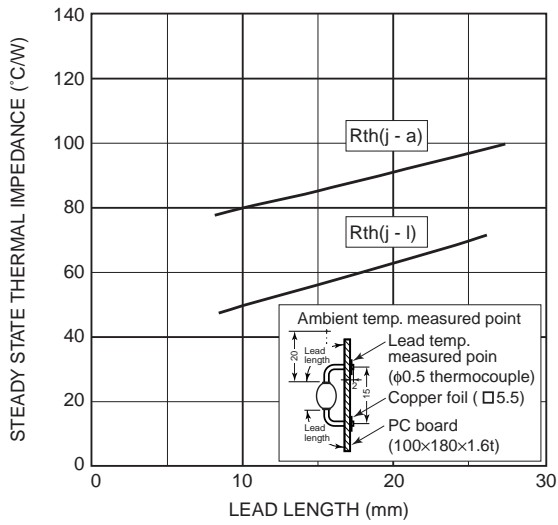
Surge forward current characteristic (Non-repetitive)



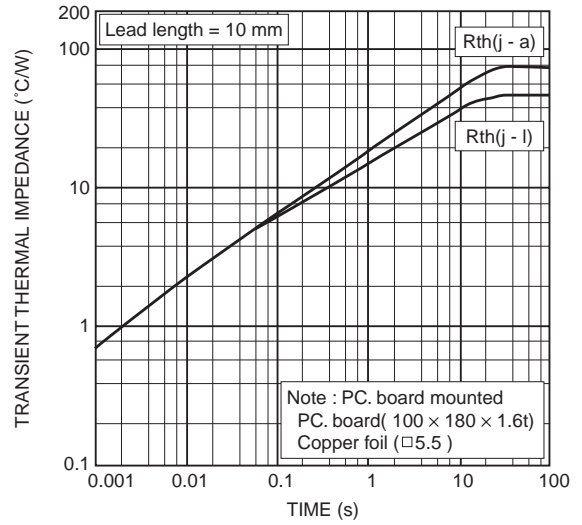
Typ. Reverse current vs. junction temperature



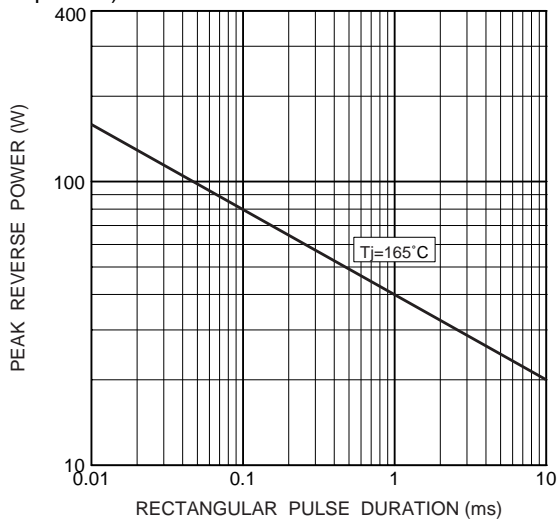
## Steady-state thermal impedance



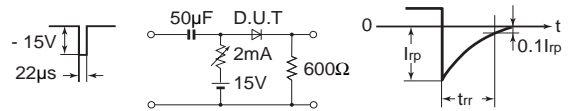
## Transient thermal impedance



## Typical reverse power characteristic (Non-repetitive)



## Reverse recovery time ( $t_{rr}$ ) test circuit



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